

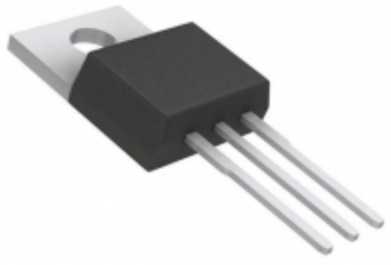


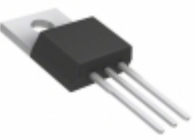
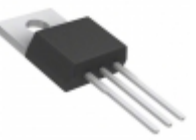



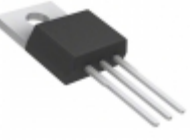
	<h2 style="color: red;">FQP6N80C</h2> <p>Hersteller-Teilenummer: FQP6N80C</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 800V 5.5A TO-220</p> <p>Datenblätter:  1.FQP6N80C.pdf  2.FQP6N80C.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 28159 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="font-size: small;">YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP6N80C
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 800V 5.5A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	28159 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	158W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.5A (Tc)
Rds On (Max) @ Id, Vgs	2.5 Ohm @ 2.75A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1310pF @ 25V
Verpackung	Tube














































FQP6N80C ist neu im Original, Suche FQP6N80C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP6N80C Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQP6N80C: Info@Y-IC.com

Sie können auch interessiert sein:

 FQP6N90 Fairchild/ON Semiconductor MOSFET N-CH 900V 5.8A TO-220	 FQP6N90C AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 6A TO-220	 FQP6N80 Fairchild/ON Semiconductor MOSFET N-CH 800V 5.8A TO-220	 FQP6N70 AMI Semiconductor / ON Semiconductor MOSFET N-CH 700V 6.2A TO-220
 FQP6N90C Fairchild/ON Semiconductor MOSFET N-CH 900V 6A TO-220	 FQP6N80 AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 5.8A TO-220	 FQP6N90 AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 5.8A TO-220	 FQP6N70 Fairchild/ON Semiconductor MOSFET N-CH 700V 6.2A TO-220

heiße Teile

Mehr

 FQP55N06	 FQP55N06	 FQP55N10	 FQP55N10	 FQP58N08
 FQP58N08	 FQP5N20L	 FQP5N20L	 FQP5N50C	 FQP5N50C
 FQP5N60C	 FQP5N60C	 FQP630TSTU	 FQP630TSTU	 FQP65N06
 FQP65N06	 FQP6N40C	 FQP6N40C	 FQP6N40CF	 FQP6N40CF
 FQP6N50C	 FQP6N50C	 FQP6N60C	 FQP6N60C	 FQP6N80C
 FQP6N90C	 FQP6N90C	 FQP70N03L	 FQP70N06	 FQP70N06C
 FQP70N08	 FQP70N08	 FQP70N10	 FQP70N10	 FQP7N10L
 FQP7N10L	 FQP7N20L	 FQP7N20L	 FQP7N60C	 FQP7N65C
 FQP7N65C	 FQP7N80C	 FQP7N80C	 FQP85N06	 FQP85N06
 FQP8N50C	 FQP8N60C	 FQP8N60C	 FQP8N65C	 FQP8N80C

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